



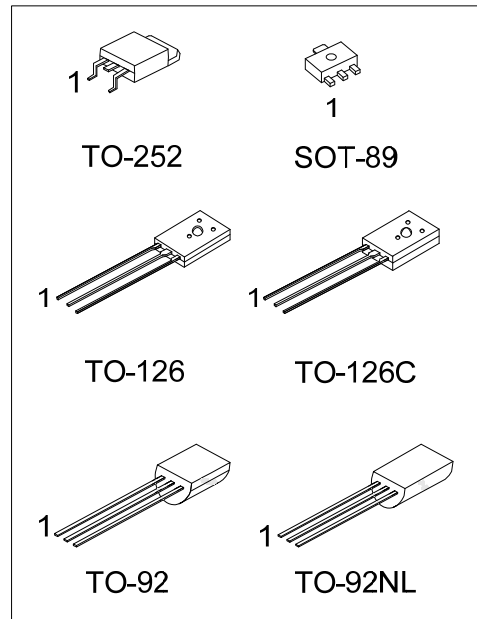
2SB649/A

PNP SILICON TRANSISTOR

BIPOLAR POWER GENERAL PURPOSE TRANSISTOR

■ APPLICATIONS

* Low frequency power amplifier complementary pair with UTC 2SB669/A



Lead-free: 2SB649L/2SB649AL
Halogen-free: 2SB649G/2SB649AG

■ ORDERING INFORMATION

Order Number			Package	Pin Assignment			Packing
Normal	Lead Free Plating	Halogen Free		1	2	3	
2SB649-x-AB3-R	2SB649L-x-AB3-R	2SB649G-x-AB3-R	SOT-89	B	C	E	Tape Reel
2SB649-x-T6C-K	2SB649L-x-T6C-K	2SB649G-x-T6C-K	TO-126C	E	C	B	Bulk
2SB649-x-T60-K	2SB649L-x-T60-K	2SB649G-x-T60-K	TO-126	E	C	B	Bulk
2SB649-x-T92-B	2SB649L-x-T92-B	2SB649G-x-T92-B	TO-92	E	C	B	Tape Box
2SB649-x-T92-K	2SB649L-x-T92-K	2SB649G-x-T92-K	TO-92	E	C	B	Bulk
2SB649-x-T9N-B	2SB649L-x-T9N-B	2SB649G-x-T9N-B	TO-92NL	E	C	B	Tape Box
2SB649-x-T9N-K	2SB649L-x-T9N-K	2SB649G-x-T9N-K	TO-92NL	E	C	B	Bulk
2SB649-x-TN3-R	2SB649L-x-TN3-R	2SB649G-x-TN3-R	TO-252	B	C	E	Tape Reel
2SB649A-x-AB3-R	2SB649AL-x-AB3-R	2SB649AG-x-AB3-R	SOT-89	B	C	E	Tape Reel
2SB649A-x-T6C-K	2SB649AL-x-T6C-K	2SB649AG-x-T6C-K	TO-126C	E	C	B	Bulk
2SB649A-x-T60-K	2SB649AL-x-T60-K	2SB649AG-x-T60-K	TO-126	E	C	B	Bulk
2SB649A-x-T92-B	2SB649AL-x-T92-B	2SB649AG-x-T92-B	TO-92	E	C	B	Tape Box
2SB649A-x-T92-K	2SB649AL-x-T92-K	2SB649AG-x-T92-K	TO-92	E	C	B	Bulk
2SB649A-x-T9N-B	2SB649AL-x-T9N-B	2SB649AG-x-T9N-B	TO-92NL	E	C	B	Tape Box
2SB649A-x-T9N-K	2SB649AL-x-T9N-K	2SB649AG-x-T9N-K	TO-92NL	E	C	B	Bulk
2SB649A-x-TN3-R	2SB649AL-x-TN3-R	2SB649AG-x-TN3-R	TO-252	B	C	E	Tape Reel

<p>2SB649L-x-AB3-R</p> <p>(1)Packing Type (2)Package Type (3)Rank (4)Lead Plating</p>	<p>(1) B: Tape Box, K: Bulk, R: Tape Reel (2) AB3: SOT-89, T6C: TO-126C, T60: TO-126, T92: TO-92, T9N: TO-92NL, TN3: TO-252 (3) x: refer to Classification of h_{FE} (4) G: Halogen Free, L: Lead Free, Blank: Pb/Sn</p>
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■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATING	UNIT
Collector-Base Voltage		V _{CBO}	-180	V
Collector-Emitter Voltage	2SB649	V _{CEO}	-120	V
	2SB649A		-160	V
Emitter-Base Voltage		V _{EBO}	-5	V
Collector Current		I _C	-1.5	A
Collector Peak Current		I _{C(PEAK)}	-3	A
Collector Power Dissipation	TO-126/TO-126C	P _C	1.4	W
	TO-92/TO-92NL		1	W
	SOT-89		0.5	W
	TO-252		2	W
Junction Temperature		T _J	+150	°C
Storage Temperature		T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
 Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

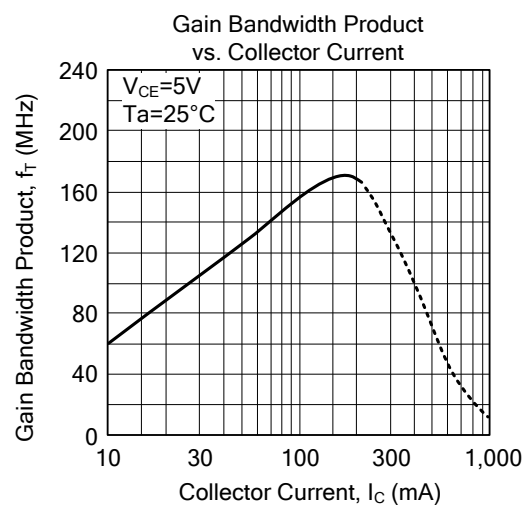
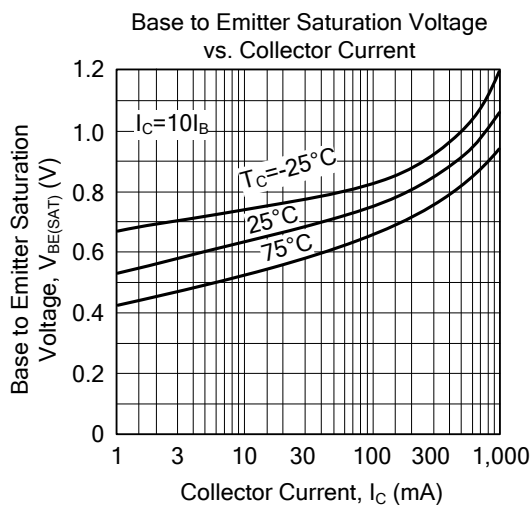
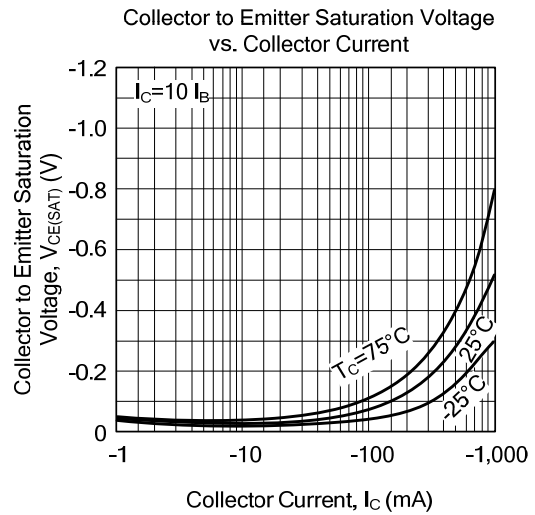
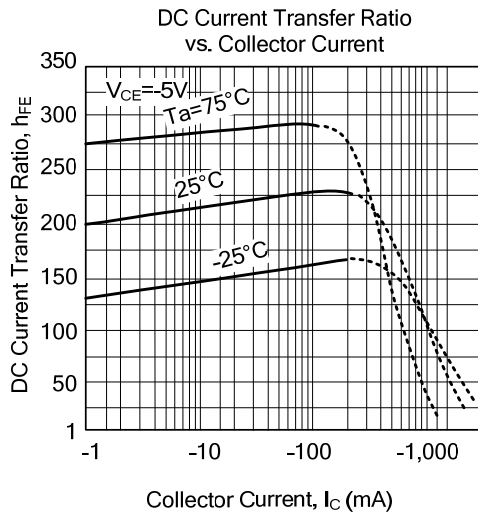
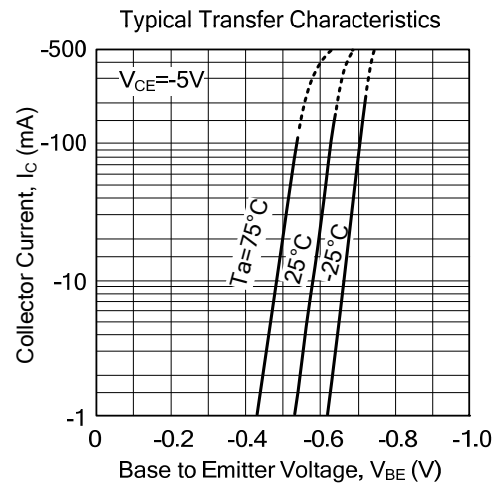
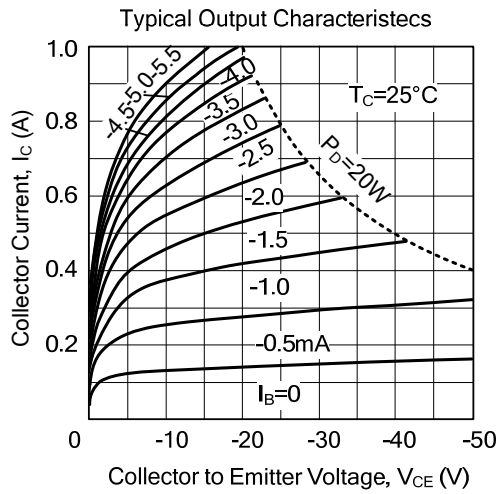
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector to Base Breakdown Voltage		BV _{CBO}	I _C =-1mA, I _E =0	-180			V
Collector to Emitter Breakdown Voltage	2SB649	BV _{CEO}	I _C =-10mA, R _{BE} =∞	-120			V
	2SB649A			-160			
Emitter to Base Breakdown Voltage		BV _{EBO}	I _E =-1mA, I _C =0	-5			V
Collector Cut-off Current		I _{CBO}	V _{CB} =-160V, I _E =0			-10	μA
DC Current Gain	2SB649	h _{FE1}	V _{CE} =-5V, I _C =-150mA (note)	60		320	
		h _{FE2}	V _{CE} =-5V, I _C =-500mA (note)	30			
	2SB649A	h _{FE1}	V _{CE} =-5V, I _C =-150mA (note)	60		200	
		h _{FE2}	V _{CE} =-5V, I _C =-500mA (note)	30			
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	I _C =-600mA, I _B =-50mA			-1	V
Base-Emitter Voltage		V _{BE}	V _{CE} =-5V, I _C =-150mA			-1.5	V
Current Gain Bandwidth Product		f _T	V _{CE} =-5V, I _C =-150mA		140		MHz
Output Capacitance		C _{ob}	V _{CB} =-10V, I _E =0, f=1MHz		27		pF

Note: Pulse test.

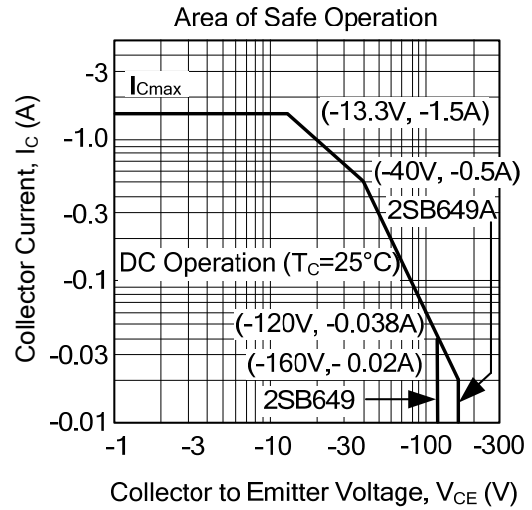
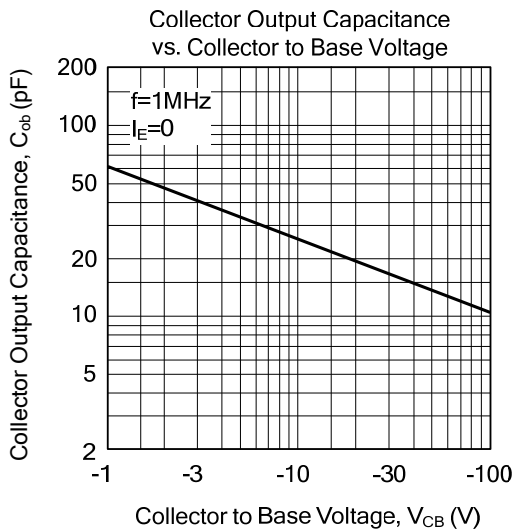
■ CLASSIFICATION OF h_{FE1}

RANGE	RANK		
	B	C	D
2SB649	60-120	100-200	160-320
2SB649A	60-120	100-200	-

TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



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